

1.2 MHz, 3A, High Efficiency Step-Down DC/DC Converter

General Description

CL3653 is a high-efficiency DC to DC step down switching regulator, capable of delivering up to 3A output current. The CL3653 operates in a wide range input voltage from 2.7V to 5.5V making the IC ideal for low voltage power conversions. Running at a fixed frequency of 1MHz allows the use of small inductance value and low DCR inductors, thereby achieving higher efficiency.

Features

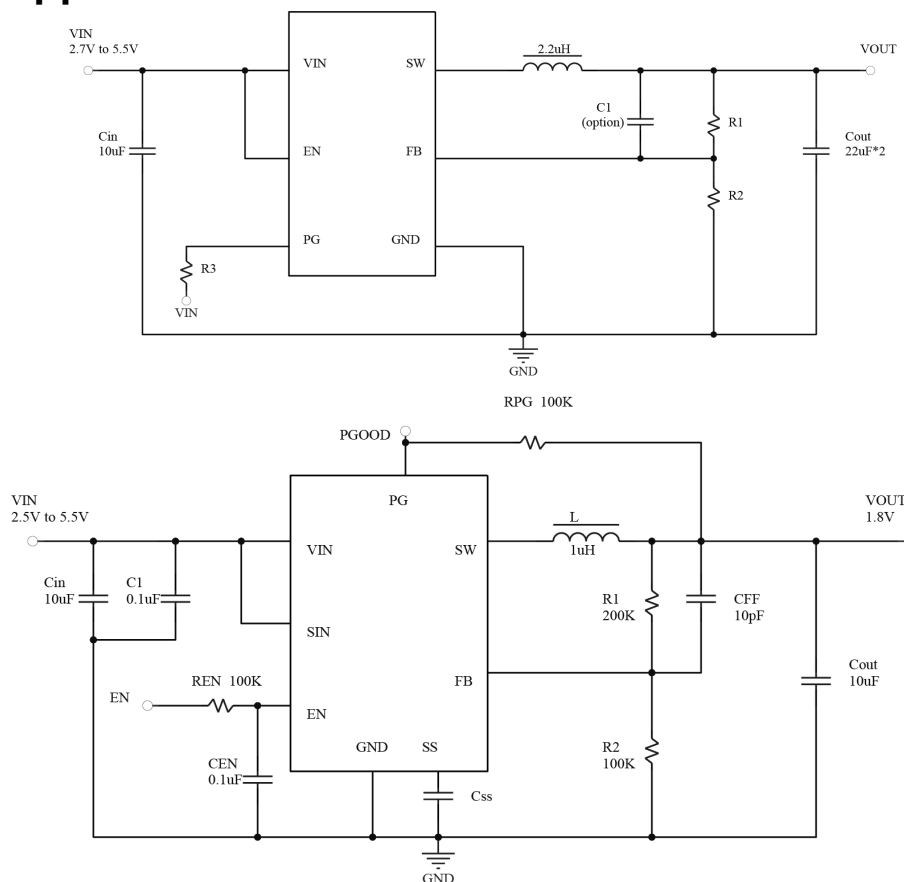
- ◆ Up to 3A Max Output Current
- ◆ 2.7V to 5.5V Input Voltage Range
- ◆ Fixed 1MHz Switching Frequency
- ◆ Short circuit protect: Latch off
- ◆ Light Load Operation
- ◆ 100% Duty Operation
- ◆ Internal Compensation
- ◆ RoHS Compliant and Halogen Free

Applications

- ◆ USB ports/Hubs
- ◆ Hot Swaps
- ◆ Cell phones
- ◆ Tablet PC
- ◆ Set Top Boxes

CL3653 is offered in SOT-23-6L to DFN3*3-10L package

Typical Application



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Pin Definition



PACKAGE	MARKING	MARKING DESCRIPTION
LEFT	CL3653	Chip Type Number
	C	Working Frequency
	A	High efficiency without light load
	YY	Year Number
	WW	Week Number

Pin Description

Pin Num	Pin Name	
	SOT23-6	DFN3*3-10
1	EN	SW
2	GND	SW
3	SW	SW
4	VIN	PG
5	PG	EN
6	FB	FB
7		SS
8		VIN
9		VIN
10		VIN

Name	Description
EN	Turns on/turns off control input
GND	Power ground pin
SW	Inductor pin. Connect this pin to the switching node of inductor
VIN	Power input pin
PG	Power good indicator. The pullup resistor can be connected to voltages up to 5V. If unused, leave it floating.
FB	Output feedback pin
SS	Soft-start programming pin, connect a capacitor from this pin to ground to program the soft-start time. As CL3653 also has internal 1ms soft-start, the actual soft-start time will be the longer one of the programmed value and the internal value. TSS=Max(1ms,0.6V*Css/2uA)

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ESD AND LATCH-UP GRADE

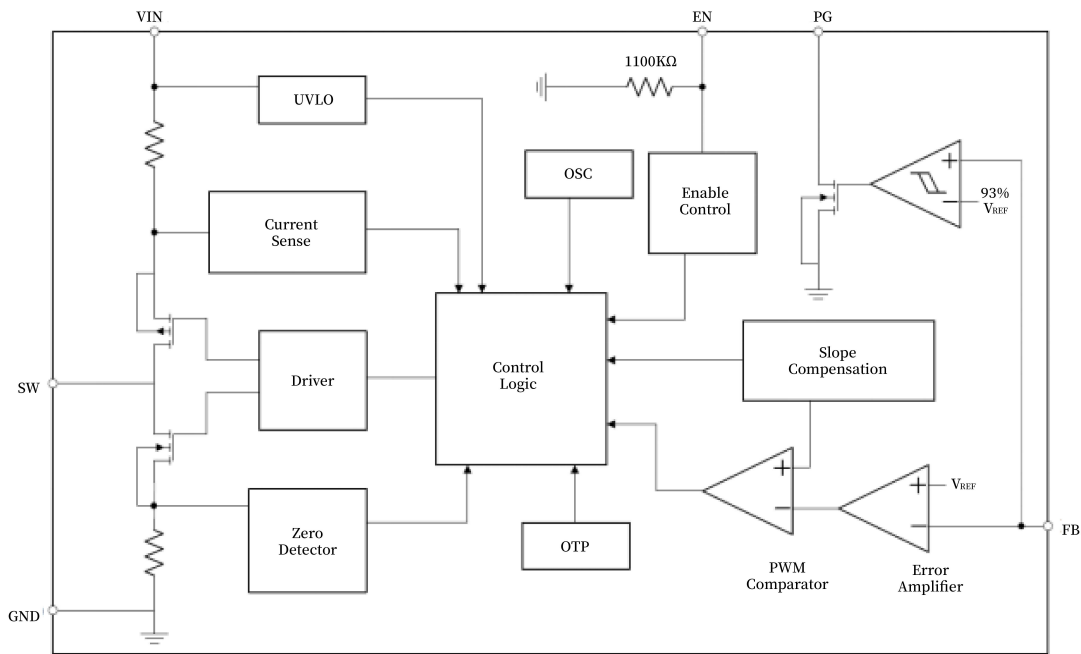
Human body model ESD level	2000V
Machine mode ESD level	200 V

ABSOLUTE MAXIMUM RATINGS

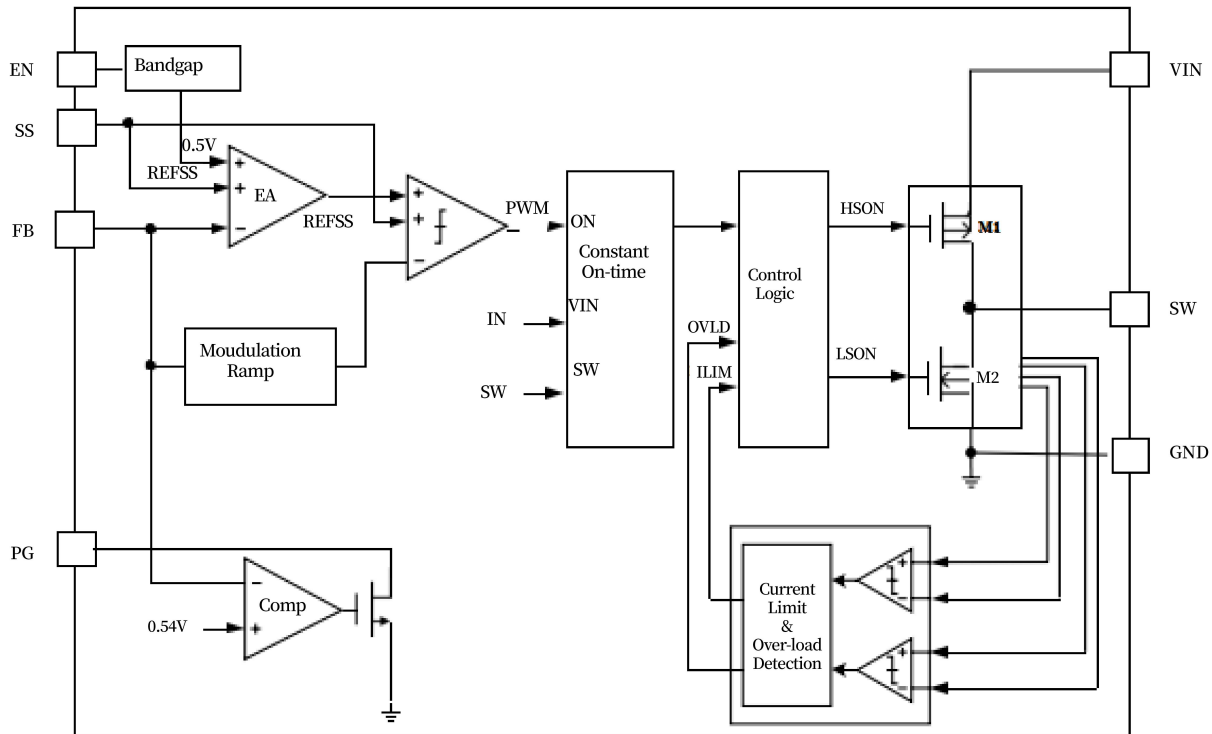
PARAMETER	SYMBOL	RATING	UNITS
INPUT VOLTAGE	V_{IN}	6	V
SW (DC) VOLTAGE	$V_{SW (DC)}$	$V_{SS}-0.3 \sim V_{out}+0.3$	V
SW (AC, less than 10nS) VOLTAGE	$V_{SW (AC)}$	$V_{SS}-0.3 \sim V_{out}+6$	V
FB VOLTAGE	V_{FB}	$V_{SS}-0.3 \sim V_{out}+6$	V
OPERATING TEMP.	T_J	-40 ~ +150	
STORAGE TEMP.	T_{stg}	-55 ~ +150	°C
LEAD TEMP.	T_{solder}	260°C, 10s	

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Block Dingram:SOT23-6L



Block Dingram:DFN3*3-10



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Electrical Characteristics

($V_{IN}=5V$, $T_A = 25^{\circ}C$ unless otherwise specified)

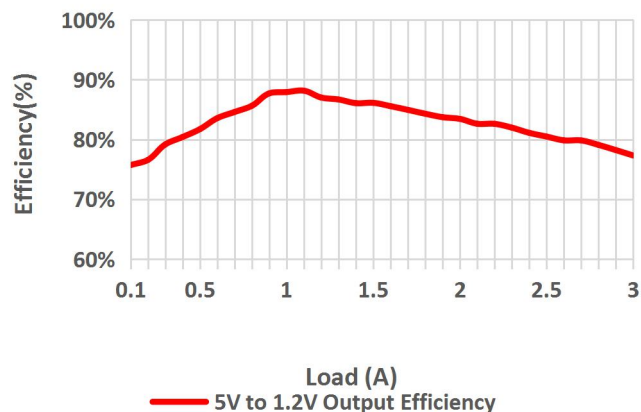
Parameters	Condition	Min	Typ	Max	Units
Input Voltage		2.7		5.5	V
UVLO Threshold			2.5		V
UVLO Hysteresis			0.15		V
Quiescent Current	$V_{FB} = 0.7V$		50		μA
Shutdown Supply Current	$V_{EN}=0V$			1	μA
Reference Voltage	$V_{IN}=2.7$ to $5.5V$	0.591	0.6	0.609	V
Reference Current			0.01		μA
Maximum Duty		100			%
Switching Frequency			1		MHz
Internal Soft-Start Time			1		ms
High Side MOSFET On-Resistance			80		m Ω
Low Side MOSFET On-Resistance			50		m Ω
High Side MOSFET Current Limit			4.8		A
High Side MOSFET Leakage Current	$V_{IN}=5V$, $V_{FB}=0.7V$			10	μA
EN Pin Pull-Low Resistance			1100		K Ω
EN Pin Input Low Voltage				0.4	V
EN Pin Input High Voltage		1.5			V
Sink current at PG Pin	I_{SINK_PG}			1	mA
Power Good Rising Threshold			93		%
Power Good Falling Threshold			88		%
Output Discharge Switch On Resistance	$V_{EN}=0V$		60		Ω
Thermal Shutdown Temperature			160		$^{\circ}C$

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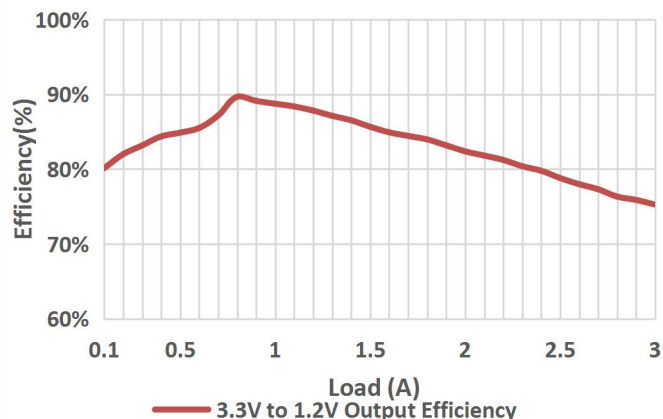
Application Performance Curves

VIN = 5 V, VOUT = 1.2 V, L = 2.2 μ H, TA = 25 °C, unless otherwise noted.

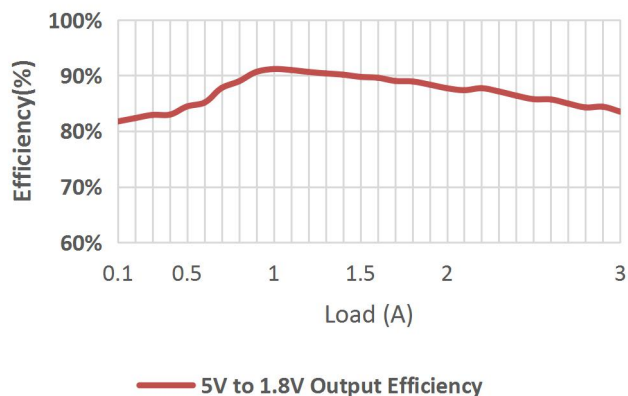
5V to 1.2V Output Efficiency



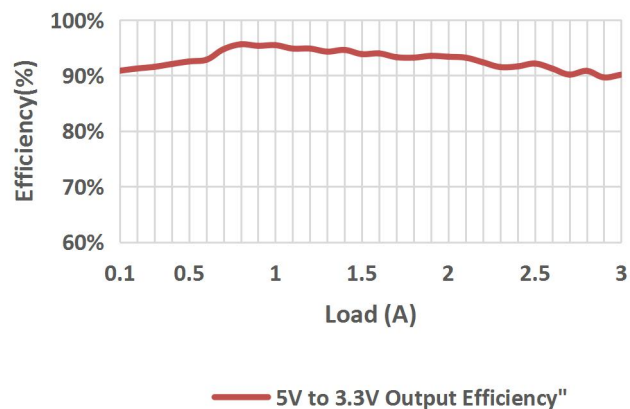
3.3V to 1.2V Output Efficiency



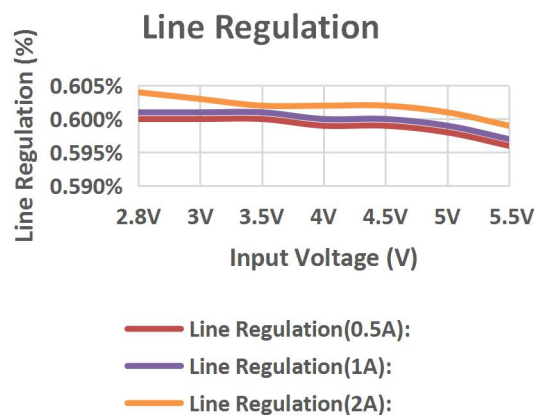
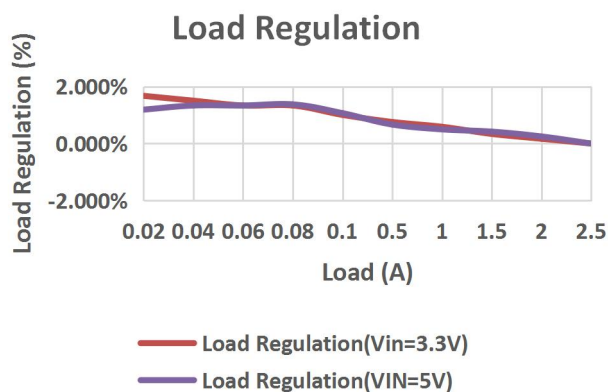
5V to 1.8V Output Efficiency



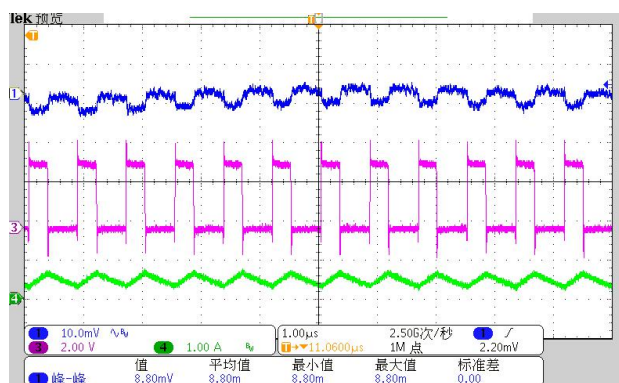
5V to 3.3V Output Efficiency



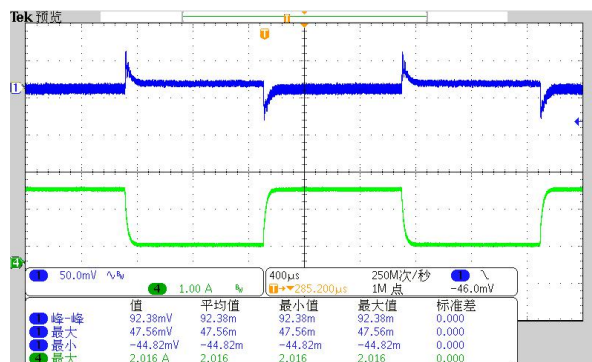
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Working waveform

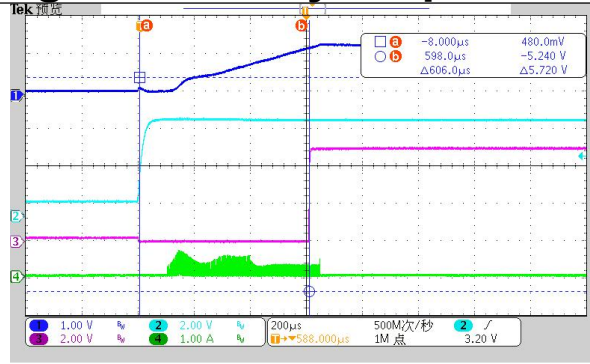


3.3V->1.2V, Iload=,500mA (Steady State Waveform)

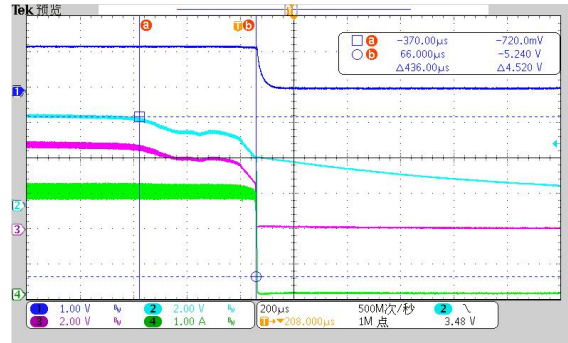


Vin=3.3V, 0.5A to 2A transient waveform (Transient Response)

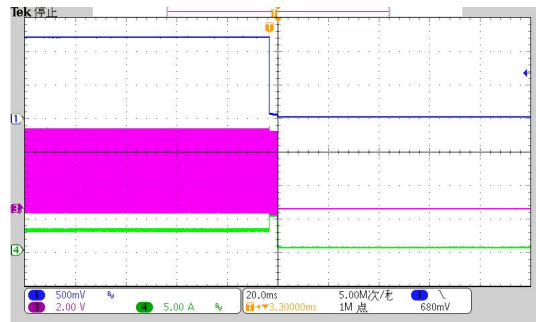
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Cin=1cm to Vin pin, Iload=0A power on (VIN Power)



Cin=1cm to Vin pin, Iload=3A power off (VIN Power)



Iload=3A short

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Function Description

CL3653 high efficiency switching regulator is a small, simple, DC-to-DC step-down converter capable of delivering up to 3A of output current. The device operates in pulse-width modulation (PWM) at 1MHz from 2.7V to 5.5V input voltage and provides an output voltage from 0.6V to VIN, making the IC ideal for on-board post-regulation applications. An internal synchronous rectifier improves efficiency and eliminates the typical Schottky free-wheeling diode. Using the on resistance of the internal high-side MOSFET to sense switching currents eliminates current-sense resistors, further improving efficiency and reducing cost.

•Loop Operation

The IC uses a PWM current-mode control scheme. An open-loop comparator compares the integrated voltage-feedback signal against the sum of the amplified current-sense signal and the slope compensation ramp. At each rising edge of the internal clock, the internal high-side MOSFET turns on until the PWM comparator terminates the on cycle. During this on-time, current ramps up through the inductor, sourcing current to the output and storing energy in the inductor. The current mode feedback system regulates the peak inductor current as a function of the output voltage error signal. During the off cycle, the internal high-side P-channel MOSFET turns off, and the internal low-side N-channel MOSFET turns on. The inductor releases the stored energy as its current ramps down.

•Current Sense

An internal current-sense amplifier senses the current through the high-side MOSFET during on time and produces a proportional current signal which is used to sum the slope compensation signal. The summed signal then is compared with the error amplifier output by the PWM comparator to terminate the on cycle.

•Current Limit

There is a cycle-by-cycle current limit on the high-side MOSFET. When the current flowing out of SW exceeds this limit, the high-side MOSFET turns off and the synchronous rectifier turns on.

•Soft-start

The IC has an internal soft-start circuit to reduce supply inrush current during startup conditions. When the device exits under-voltage lockout (UVLO), shutdown mode, or restarts following a thermal-overload event, the soft-start circuit slowly ramps up the output voltage.

•UVLO and Thermal Shutdown

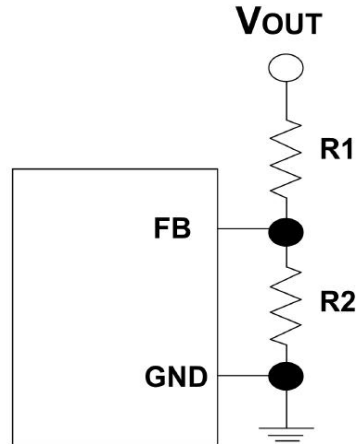
If VIN drops below 2.5V, the UVLO circuit inhibits switching. Once VIN rises above 2.7V, the UVLO clears, and the soft-start sequence activates. Thermal-overload protection limits total power dissipation in the device. When the junction temperature exceeds $T_J = +160^{\circ}\text{C}$, a thermal sensor forces the device to shutdown, allowing the die to cool down. The thermal sensor turns the device on again after the junction temperature falls below 60°C . After a thermal-shutdown condition, the soft-start sequence begins.

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Application Information

•Setting Output Voltages

The resistive voltage divider allows the FB pin to sense a fraction of the output voltage shown as below.



For adjustable voltage mode, the output voltage is set by an external resistive voltage divider according to the following equation:

$$V_{OUT} = V_{FB} \left(1 + \frac{R1}{R2} \right)$$

where V_{FB} is the feedback reference voltage (0.6V typ.).

•Inductor Selection

The peak-to-peak ripple is set to 30% of the output current. This places the peak current far enough from the minimum over current trip level to ensure reliable operation while providing enough current ripples for the current mode converter to operate stably. The inductance is determined as expressed in the following equation:

$$L \geq \frac{(V_{IN} - V_{OUT}) \times D}{\Delta I_L \times f_{SW}}$$

Where ΔI_L is the inductor peak-to-peak ripple current, D is the duty cycle determined by V_{OUT}/V_{IN} , f_{SW} is the switching frequency.

•Output Capacitor Selection

For most applications a nominal 22 μ F*2 capacitor is suitable. The output capacitor keeps output ripple small and ensures control-loop stability.

The output capacitor must also have low impedance at the switching frequency. Ceramic, polymer, and Tantalum capacitors are suitable, with ceramic exhibiting the lowest ESR and high-frequency impedance. Output ripple with a ceramic output capacitor is approximately as follows:

$$\Delta V_{OUT} \leq \Delta I_L \left[ESR + \frac{1}{8f_{SW}C_{OUT}} \right]$$

•Input Capacitor Selection

The input capacitance, C_{IN} , is needed to filter the trapezoidal current at the source of the top MOSFET. To prevent large ripple current, a low ESR input capacitor sized for the maximum RMS current should be used. The RMS current is given by :

$$I_{RMS} = I_{OUT} \times \sqrt{D \times (1 - D)}$$

This formula has a maximum at $V_{IN} = 2V_{OUT}$, where $I_{RMS} = I_{OUT}/2$

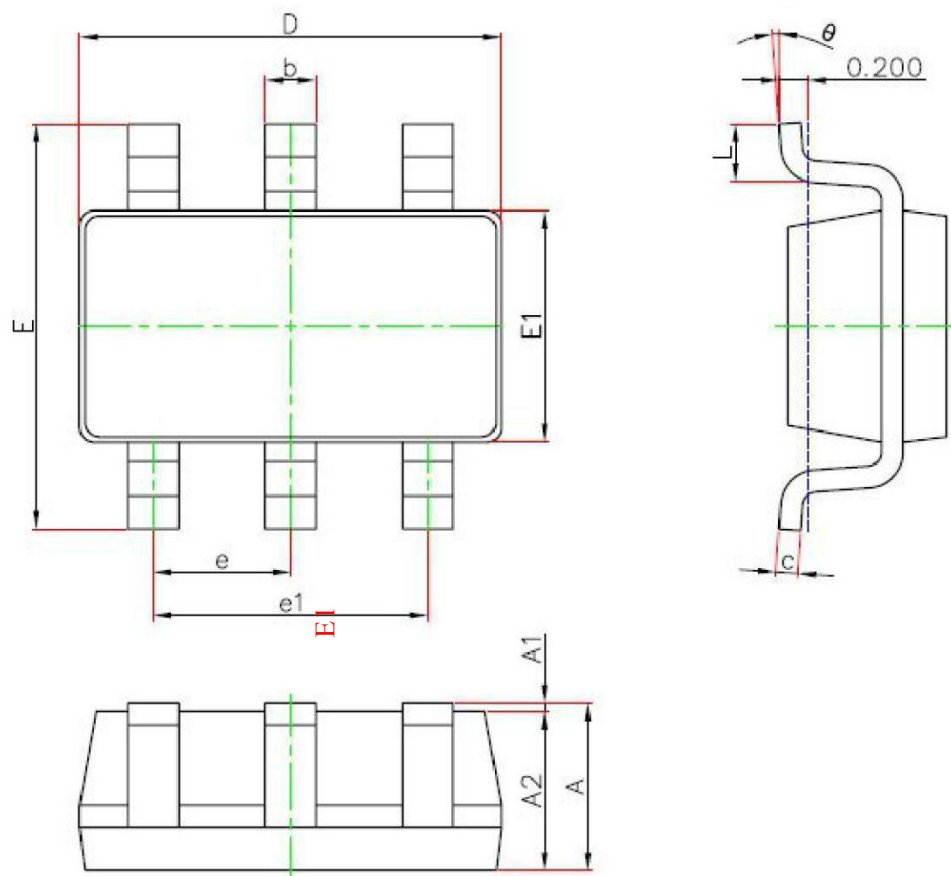
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•Power Good Function

PG pin for CL3653 is an open drain input, when output voltage higher than 92% setting value, the state is high. If the output voltage is less than 88%, the state will change to low. Recommend the value of pull up resistor is from 50Kohm to 100Kohm to take better performance.

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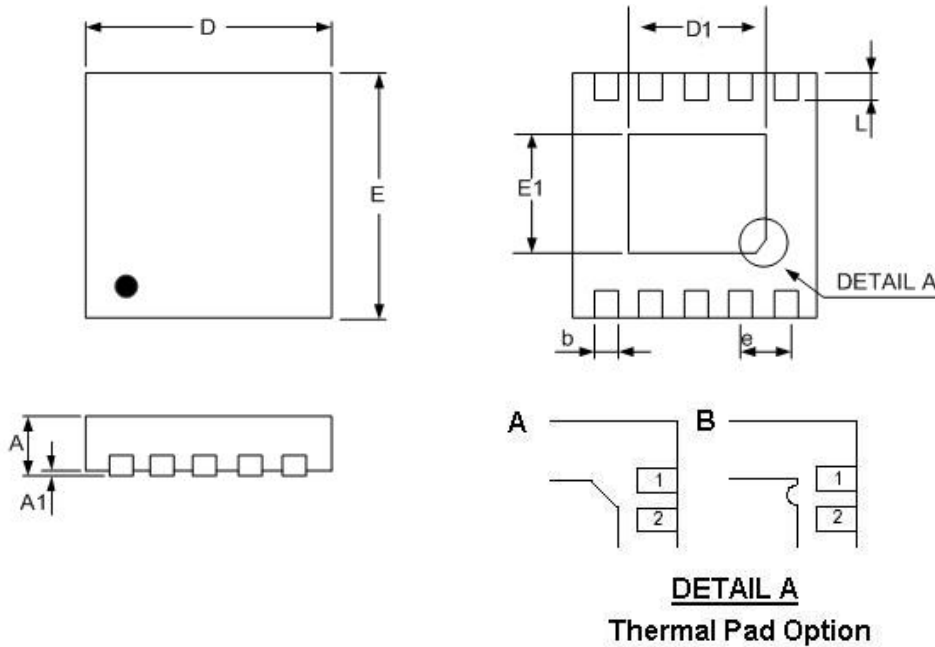
Package Mechanical Data : SOT-23-6L



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
theta	0°	8°	0°	8°

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Package Mechanical Data : DFN3*3-10L



SYMBOLS	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	0.70	0.80	0.028	0.031
A1	0.00	0.05	0.000	0.002
b	0.18	0.30	0.007	0.012
D	2.90	3.10	0.114	0.122
D1	2.10	2.60	0.083	0.102
E	2.90	3.10	0.114	0.122
E1	1.35	1.75	0.053	0.069
e	0.50		0.020	
L	0.30	0.50	0.012	0.020

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